

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L7	0	((thin adj film) TFT) AND ((channel) (semiconductor adj (film layer))) AND (laser same (anneal\$5 irradiat\$5)) AND (crystal\$5 adj boundary)).CLM.	US-PGPUB	OR	ON	2006/08/31 12:16
L8	37	((heterogeneous (crystal\$5 adj2 boundary)) AND ((semiconduct\$5 adj channel) (channel)) AND ((thin adj film adj transistor) TFT)).CLM.	US-PGPUB	OR	ON	2006/08/31 12:18

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Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("20040218109").PN.	US-PGPUB; USPAT	OR	OFF	2006/08/31 12:00
L2	101287	((thin adj film) TFT) and ((channel) (semiconductor adj (film layer)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:15
L3	8738	2 and ("349"/\$.ccls. 257/59,72. ccls. 345/92.ccls.)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:12
L4	2017	3 and (laser same (anneal\$5 irradiat\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:14
L5	81	4 and (crystal\$5 adj boundary)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:20
L6	140	((thin adj film) TFT) AND ((channel) (semiconductor adj (film layer))) AND (laser same (anneal\$5 irradiat\$5)) AND (crystal\$5 adj boundary)	US-PGPUB	OR	ON	2006/08/31 12:19
L9	287	((thin adj film) TFT) AND ((channel) (semiconductor adj (film layer))) AND (laser same (anneal\$5 irradiat\$5)) AND (crystal\$5 adj boundary)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:19
L10	222	9 and @ad<"20040112"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/31 12:21